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WHAT IS CLAIMED IS:

ioombada leesok

1. An X-ray detecting device, comprising:

a thin film transistor having a gate electrode, a source electrode and a drain electrode provided on a substrate;

- a first protective film covering the thin film transistor;
- a first drain contact hole passing through the first protective film;
- a second protective film provided on the first protective film;
- a second drain contact hole passing through the second protective film centering around the drain contact hole; and
- a transparent electrode connected to the drain electrode via the first and second drain contact holes.
- 2. The X-ray detecting device according to claim 1, wherein the second drain contact hole has a smaller width than the first drain contact hole.
- 3. The X-ray detecting device according to claim 1, further comprising:
 - a ground line having the lower electrode of a storage capacitor on the substrate;
- a first storage contact hole passing through the first protective film covering the ground line;
 - a second storage contact hole passing through the second protective film centering

around the first storage contact hole; and

a storage electrode electrically connected to the ground line via the first and second storage contact holes.

- 4. The X-ray detecting device according to claim 3, wherein the first protective film is made from an inorganic insulating material.
- 5. The X-ray detecting device according to claim 3, wherein the second protective film is made from an organic insulating material.
- 6. The X-ray detecting device according to claim 5, further comprising:
 - a third protective film provided on the second protective film; and
- a pixel electrode electrically connected to the drain electrode via a contact hole passing through the third protective film.
- 7. The X-ray detecting device according to claim 3, further comprising:
 - a third protective film provided on the second protective film; and
- a pixel electrode electrically connected to the drain electrode via a contact hole passing through the third protective film.
- 8. The X-ray detecting device according to claim 3, wherein the second storage contact hole has a smaller width than the first storage contact hole.
- 9. A method of fabricating an X-ray detecting device, comprising the steps of:

providing a gate electrode on a substrate;

providing a gate insulating film on the substrate;

providing a semiconductor layer on the gate insulating film;

providing a source electrode and a drain electrode on the gate insulating film;

providing a first protective film on the gate insulating film;

providing a first drain contact hole passing through the first protective film;

providing a second protective film on the first protective film;

providing a second drain contact hole passing through the second protective film centering around the first drain contact hole; and

providing a transparent electrode on the second protective film.

- 10. The method according to claim 9, wherein the first drain contact hole has a larger width than the second drain contact hole.
- 11. The method according to claim 9, further comprising the steps of:

forming a ground line simultaneously with the source and drain electrodes;

forming a first storage contact hole passing through the first protective film covering the ground line;

forming a second storage contact hole passing through the second protective film

centering around the first storage contact hole; and

forming a transparent electrode on the second protective film.

- 12. The method according to claim 11, further comprising the steps of:
 forming a third protective film on the second protective film; and
 - forming a pixel electrode on the third protective film.
- 13. The method according to claim 11, wherein the first storage contact hole has a larger width than the second storage contact hole.
- 14. The method according to claim 11, wherein the first protective film is made from an inorganic insulating material.
- 15. The method according to claim 11, wherein the second protective film is made from an organic insulating material.